NSN 5961-01-239-4509

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-239-4509 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Terminal Length:** 0.150 inches **Overall Height:** 0.300 inches **Overall Width:** 0.280 inches **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc all transistor and 30.0 collector to emitter voltage/static/base open all transistor and 5.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 4.6 watts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 50.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 14 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:** No